

PSMN7R8-100PSE

N-channel 100 V 7.8 m $\!\Omega$ standard level MOSFET with improved SOA in TO220 package

11 August 2014

Product data sheet

1. General description

Standard level N-channel MOSFET with improved SOA in a TO220 package. Part of Nexperia "NextPower Live" portfolio, the PSMN7R8-100PSE is robust enough to withstand substantial in-rush and fault condition currents during turn on/off, whilst offering a low RDS(on) characteristic to keep temperatures down and efficiency up in continued use. Ideal for telecommunication systems based on 48 V backplanes / supply rails.

2. Features and benefits

- Enhanced safe operating area (SOA) for superior protection during linear mode operation
- Low RDS(on) for low conduction losses

3. Applications

- Electronic fuse
- Hot-swap / Soft-start
- Uninterruptible power supplies
- Motor control

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V_{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	-	100	V	
I _D	drain current	T _{mb} = 100 °C; V _{GS} = 10 V; <u>Fig. 2</u>		-	-	83	Α	
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	294	W	
Static characte	Static characteristics							
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 12		-	6.7	7.8	mΩ	
Dynamic chara	Dynamic characteristics							
Q_{GD}	gate-drain charge	V _{GS} = 10 V; I _D = 25 A; V _{DS} = 50 V;		-	41	-	nC	
Q _{G(tot)}	total gate charge	Fig. 14; Fig. 15		-	128	-	nC	



Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Avalanche rug	gedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 100 A; V_{sup} ≤ 100 V; R_{GS} = 50 Ω ; unclamped; Fig. 4	-	-	315	mJ

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D I
2	D	drain	704	
3	S	source		G UNA
mb	D	mounting base; connected to drain		mbb076 S
			TO-220AB (SOT78)	

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PSMN7R8-100PSE	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78		

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN7R8-100PSE	PSMN7R8-100PSE

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	100	V

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Symbol	Parameter	Conditions		Min	Max	Unit
V_{DGR}	drain-gate voltage	$T_j \ge 25$ °C; $T_j \le 175$ °C; $R_{GS} = 20$ kΩ		-	100	V
V_{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	294	W
I _D	drain current	V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 2</u>	[1]	-	100	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	83	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3		-	473	Α
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drai	n diode					
I _S	source current	T _{mb} = 25 °C	[1]	-	100	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	473	Α
Avalanche r	ruggedness			'		,
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_{D} = 100 A; $V_{sup} \le$ 100 V; R_{GS} = 50 Ω; unclamped; Fig. 4		-	315	mJ

[1] Continuous current limited by package

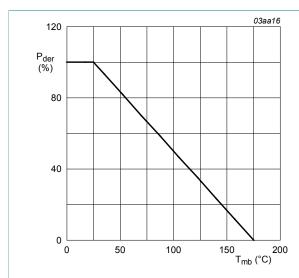
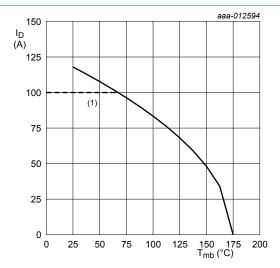


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

$$P_{\textit{der}} = \frac{P_{\textit{tot}}}{P_{\textit{tot}(25^{\circ}\textit{C})}} \times \textbf{100 \%}$$



(1) Capped at 100A due to package

Fig. 2. Continuous drain current as a function of mounting base temperature

$$V_{\rm GS} \geq 10 V$$

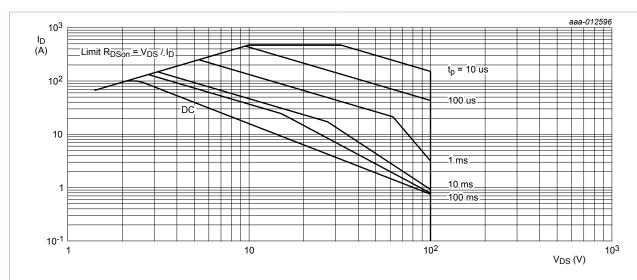


Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage



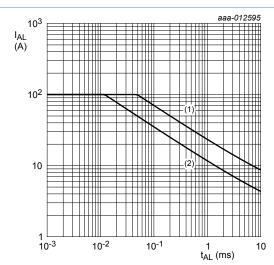


Fig. 4. Single pulse avalanche rating; avalanche current as a function of avalanche time

(1)
$$T_{j (init)} = 25^{\circ}C$$
; (2) $T_{j (init)} = 100^{\circ}C$

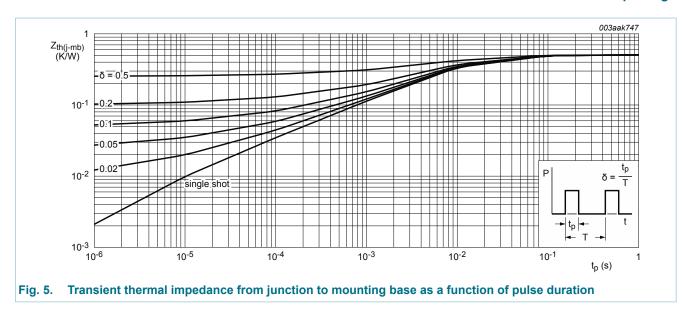
9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	0.42	0.51	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	Minimum footprint; mounted on a printed circuit board	-	50	-	K/W

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
Static characteristics								
$V_{(BR)DSS}$	drain-source	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	100	-	-	V		
	breakdown voltage	I_D = 250 μ A; V_{GS} = 0 V; T_j = -55 °C	90	-	-	V		
$V_{GS(th)}$	gate-source threshold voltage	I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 25 °C; Fig. 10; Fig. 11	2	3	4	V		
V_{GSth}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ Fig. 11	1	-	-	V		
	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 11	-	-	4.6	V			
I _{DSS}	drain leakage current	V _{DS} = 100 V; V _{GS} = 0 V; T _j = 25 °C	-	0.1	2	μA		
		V _{DS} = 100 V; V _{GS} = 0 V; T _j = 175 °C	-	-	500	μA		
I _{GSS}	gate leakage current	V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA		
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA		
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 12	-	6.7	7.8	mΩ		
		V _{GS} = 10 V; I _D = 25 A; T _j = 100 °C; Fig. 12; Fig. 13	-	-	14	mΩ		
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 12; Fig. 13	-	-	21	mΩ		
R _G	gate resistance	f = 1 MHz	0.42	0.83	1.66	Ω		

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic ch	naracteristics		'			
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 50 V; V _{GS} = 10 V; Fig. 14; Fig. 15	-	128	-	nC
	I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V	-	110	-	nC	
Q_{GS}	gate-source charge	I _D = 25 A; V _{DS} = 50 V; V _{GS} = 10 V;	-	33	-	nC
Q_GD	gate-drain charge	Fig. 14; Fig. 15	-	41	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	I _D = 25 A; V _{DS} = 50 V; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	5.3	-	V
C _{iss}	input capacitance	V _{DS} = 50 V; V _{GS} = 0 V; f = 1 MHz;	-	7110	-	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 16</u>	-	450	-	pF
C _{rss}	reverse transfer capacitance		-	310	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 50 \text{ V}; R_L = 2 \Omega; V_{GS} = 10 \text{ V};$	-	31	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$	-	48	-	ns
t _{d(off)}	turn-off delay time		-	82	-	ns
t _f	fall time		-	47	-	ns
Source-dra	in diode					
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 17</u>	-	0.8	1.2	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$	-	69	-	ns
Q _r	recovered charge	V _{DS} = 50 V	-	210	-	nC

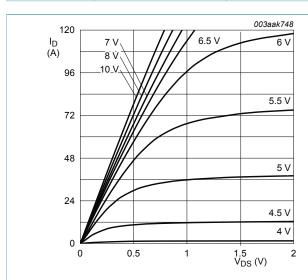


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values $T_j = 25^{\circ}C$

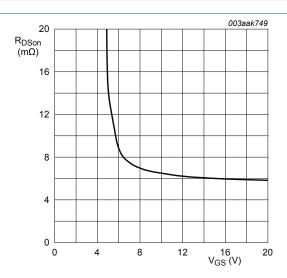


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25^{\circ}C; I_D = 25A$$

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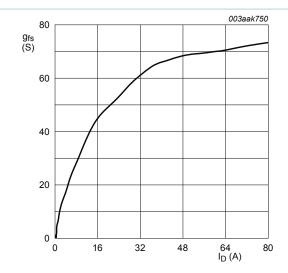


Fig. 8. Forward transconductance as a function of drain current; typical values

$$T_j = 25^{\circ}C; \ V_{DS} = 10V$$

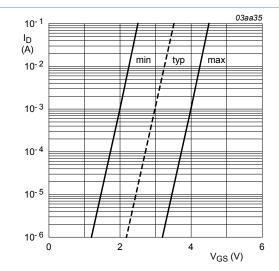


Fig. 10. Sub-threshold drain current as a function of gate-source voltage

$$T_j=25\,^{\circ}C; V_{DS}=5V$$

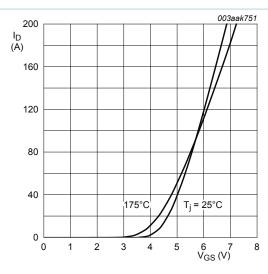


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

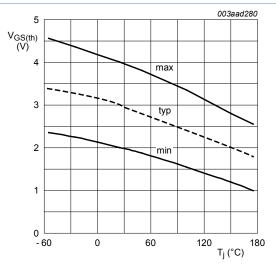


Fig. 11. Gate-source threshold voltage as a function of junction temperature

$$I_D = 1 \text{ mA}; V_{DS} = V_{GS}$$

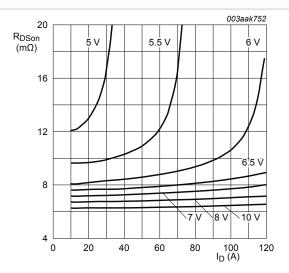


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25^{\circ}C$$

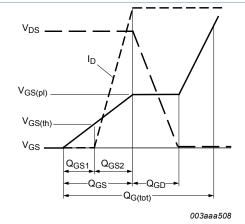


Fig. 14. Gate charge waveform definitions

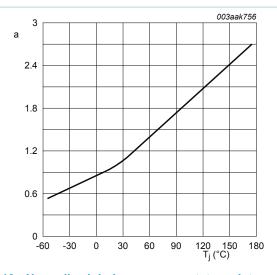


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon (25^{\circ}C)}}$$

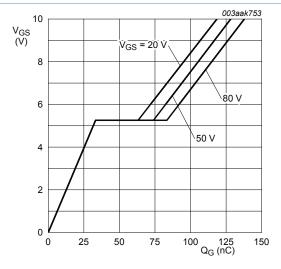


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$$T_i = 25$$
°C; $I_D = 25$ A

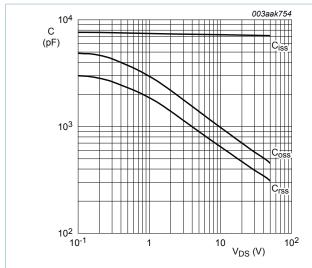


Fig. 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



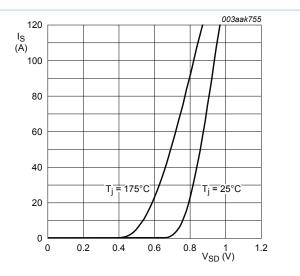
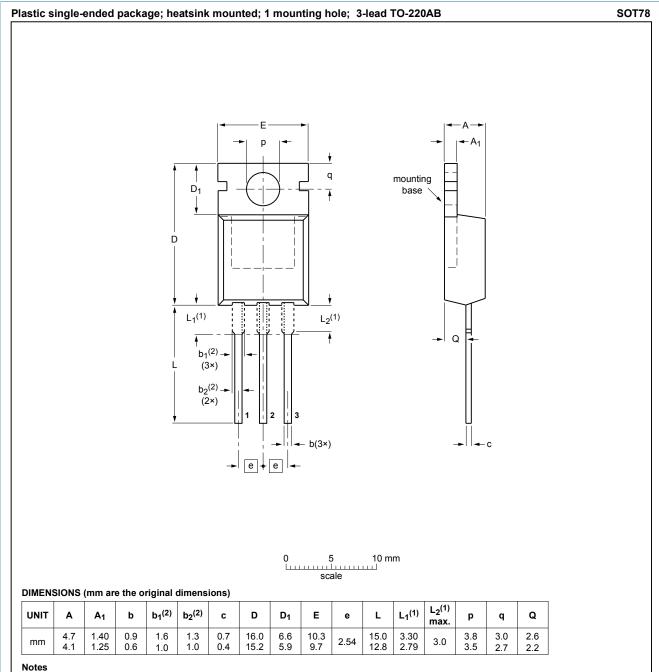


Fig. 17. Source current as a function of source-drain voltage; typical values

$$V_{GS} = 0V$$

11. Package outline



- 1. Lead shoulder designs may vary.
- Dimension includes excess dambar.

OUTLINE		REFERENCES				ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	
SOT78		3-lead TO-220AB	SC-46			08-04-23 08-06-13

Fig. 18. Package outline TO-220AB (SOT78)

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